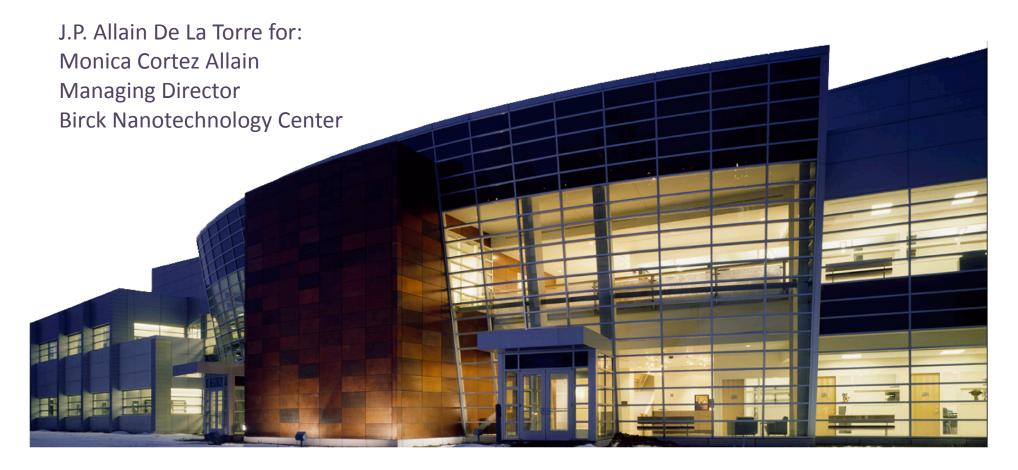
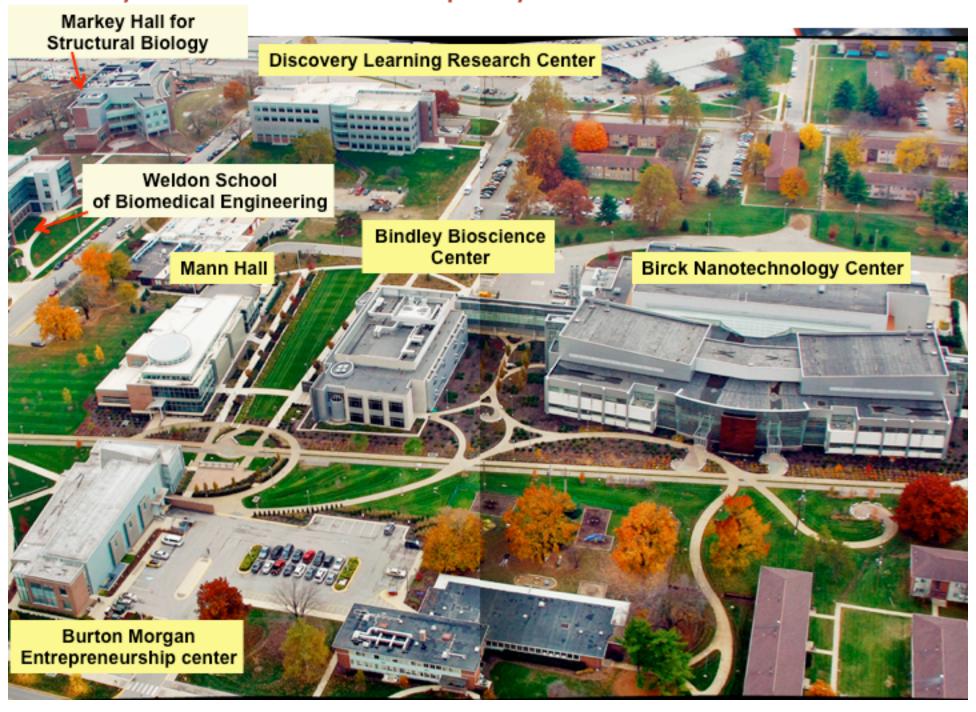
Overview of BNC Research

Collaboration, Discovery and Delivery



Discovery Park – a hub for Interdisciplinary Innovation and Commercialization



The BNC concept

- Engaging interdisciplinary, societal-scale challenges and opportunities in healthcare, information access, energy, and the environment with approaches enabled by nanoscale science and engineering
- Community encompassing a very broad span of disciplines
- In the same space to the degree possible
- The best in facilities and tools
- Everything shared
- Fluid...no "ownership" of space
- Sustainable financial model



The BNC facility – A unique instrument for nanoscale research



- •187,000 ft², \$58M + ~\$35M in equipment
- First integration of bio-pharma and semiconductor cleanroom
- •Exceptional quality cleanroom 25,000 ft²; 45 % Class 1 (ISO Class 3)

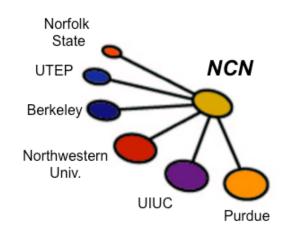


- Low Vibration (NIST A in cleanroom and A-1 in Hall lab)
- "Nanotechnology Grade" DI water plant (<15 ppt boron)
- •1, 0.1, and 0.01°C control
- Nanotech research space available for start-up companies



Research strengths

- Nanometrology
- Nanoelectronics
- Computational nanotechnology
- Nanophotonics/plasmonics
- Energy conversion
- MEMs/NEMs and microfluidics
- Nano-bio
 - Nanobiotechnology
 - Nanomedicine
 - Implantable microdevices









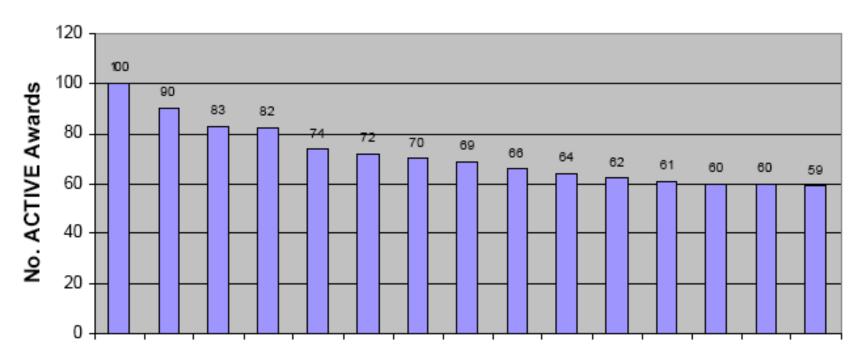
A unique instrument for nanoscale research



- Scanning Tunneling Microcsopy (STM)
 - NIST A-1 (Vibration control)
 - Temperature control (0.01°C)
 - Electromagnetic Shielding
- Scanning Probe Microcopy (SPM)
- Transmission Electron Microscopy (TEM)
- Atomic Force Microscopy (AFM)
- X-ray Photoemission Spectroscopy (XPS)
- Scanning Electron Microscopy (SEM)
- X-ray Diffraction
- Auger Electron Spectroscopy (AES)
 MUCH-MUCH More

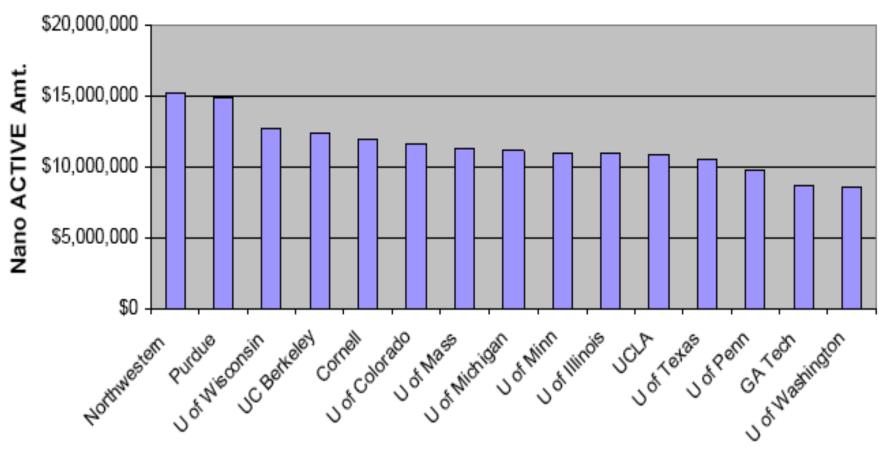


Top 15 Institutions by Number of Active NSE Awards in 2009



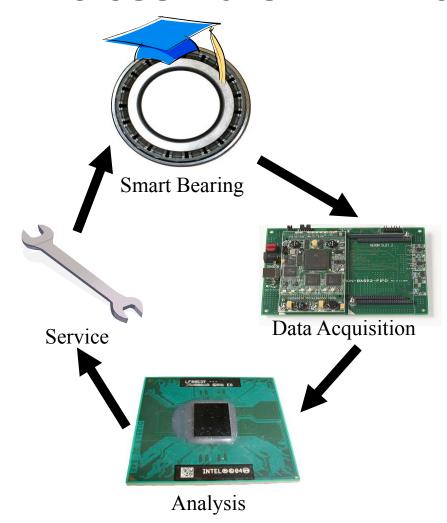


Top 15 Institutions by NSE Active Amount in 2009



M.C. Roco, NSF Nanoscale Science and Engineering Grantee's Conference, Dec.7, 2009.

Wireless Harsh-Environment MEMS Sensors

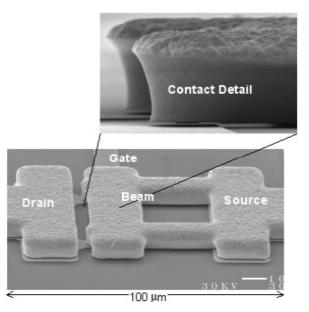


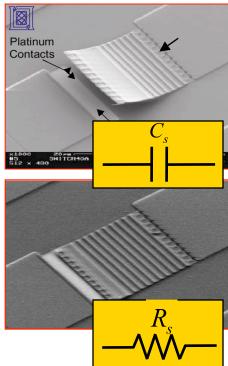


- Maintenance of military aircraft consumes a large amount of time and resources
 - CH-53E requires > 44 hours
 of maintenance / hour of
 flight time
- Limited ability for condition monitoring

MEMS . . .

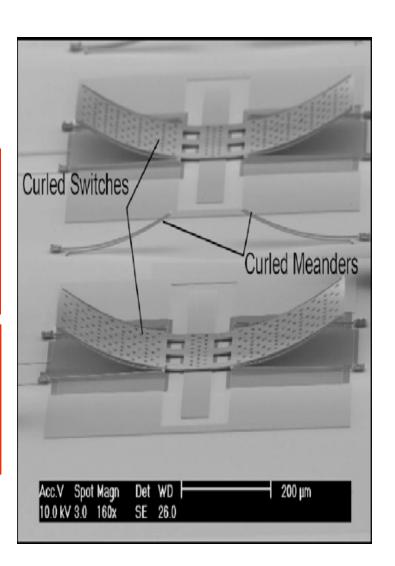
Micro-Electro-Mechanical Systems





Applications . . .

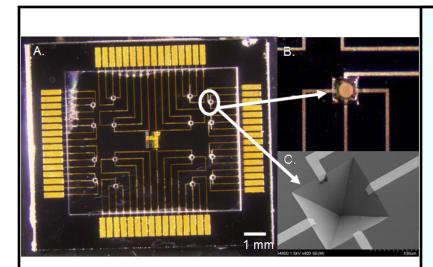
- Bearing Life Monitoring
- Switches and Capacitors in RF Circuits



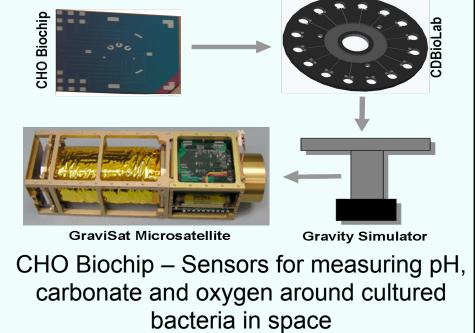
Lab-on-a-chip based Biosensors

- Lab-on-a-chips fabricated using silicon microfabrication techniques
- Wet and dry etching, metal evaporation and SU-8 photolithography
- Sensor selectivity imparted through specialized chemical formulations coated on electrodes
- Voltage or current based sensing

- Applications
 - Fundamental Biological/Biomedical Research
 - Biomedical Diagnostics
 - Environmental Monitoring
 - Agriculture

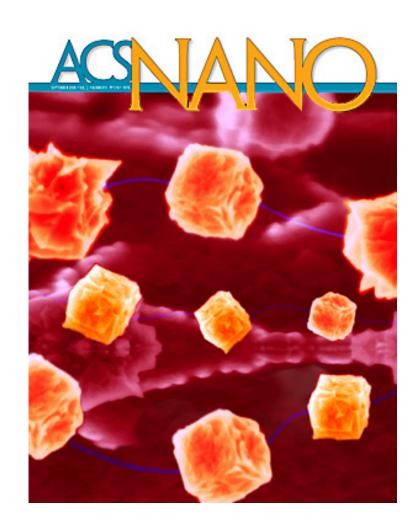


CEL-C Biochip – Sensors for Measuring calcium concentrations around single cells



Nano-tetherball biosensor

- Precisely detects glucose
- Nanotubes have a diameter (2nm)~25,000x thinner than human hair
- Sensor requires 5x less glucose to generate a signal
- Sensor has wider range of glucose concentration
- SWNT serve as electronic sensor



In the press:

Magnetic Ferro-Paper (Prof. Babek Ziaie, ECE)

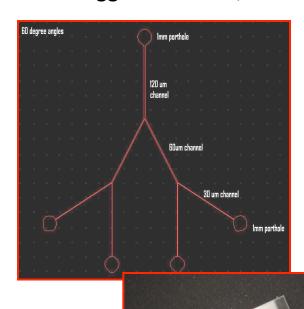
WEST LAFAYETTE, Ind. - Researchers at Purdue University have created a magnetic "ferropaper" that could be used to make low-cost "micro-motors" for surgical instruments, tiny tweezers to study cells, and miniature speakers. The research is based at the Birck Nanotechnology Center in Purdue's Discovery Park.



Example - Government-Industry-University partnership:

A Portable BioMEMS Blood Analyzer for NASA

Meggie Grafton¹⁻³, Lisa M. Reece²⁻⁴, Paul W. Todd⁵, James F. Leary¹⁻⁴



¹Weldon School of Biomedical Engineering, ²Birck Nanotechnology Center, ³Bindley Biosciences Center, ⁴Basic Medical Sciences, Purdue University ⁵Techshot, Inc. (Greenville, IN).

This NASA-SBIR funded academic-industry partnership between Purdue and Techshot, Inc, is addressing an urgent NASA need — rapid blood analyses to assess the health of astronauts in space. The portable BioMEMS device, being designed and fabricated in the Birck Nanotechnology Center, analyzes absolute red and white blood cell numbers as well as assessing the altered immune cell status of the astronauts in micro-gravity environments.

BNC Collaborations Provide..

- Collaboration with top researchers in various core areas of nanotechnology.
- Access to state-of-the-art equipment
- Resources to enhance Funding Opportunities
 - OVPR Large Proposal Development Services (>1M)
 - Proposal Preparation Resources
 - Seed Grant Programs (Internal to Purdue and in collaboration with IU and/or other institutions
 - Possible Cost sharing opportunities
- Research Space and Office of Technology Commercialization expertise

Bindley Bioscience Center



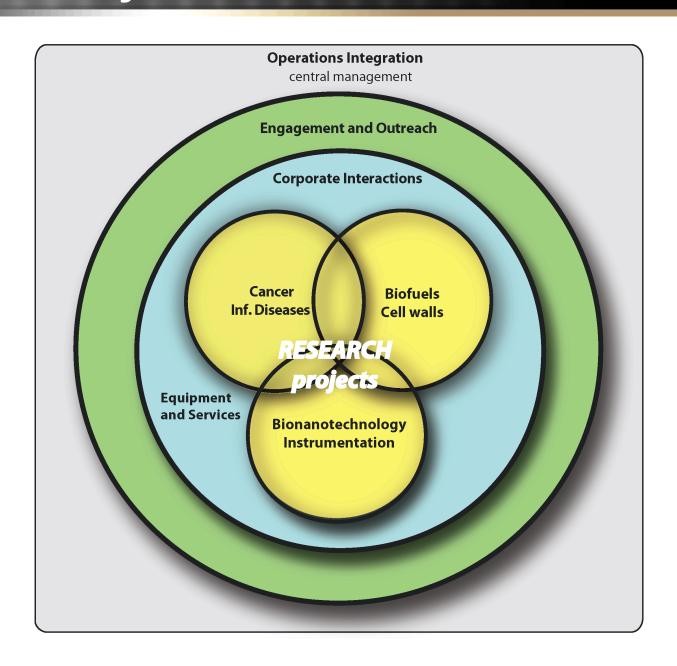
29,000 ft² of laboratory space for interdisciplinary life sciences & bioengineering Shared faculty offices \$15 million 2-story structure

Skywalk to Birck Nanotechnology Center

Flexible Research Space

- Creates an open environment for interactive communication.
- Allows for dynamic lab spaces rather than disciplinary-defined labs for:
 - Biomolecular technologies (esp. metabolomics and proteomics)
 - Advanced imaging. cytometry, high speed cell sorting
 - Biophysical analysis. physiological biosensor development
 - Integrated screening (high content, chemical and biological screening, protein expression)
 - Center for Global Research and Intervention in Infectious Diseases (cGRIID)
 - Center for Analytical Instrumentation Development (CAID)
 - · Nanochemistry, biopolymer synthesis
 - Computational biology, bioinformatics and systems biology

The Bindley 2010

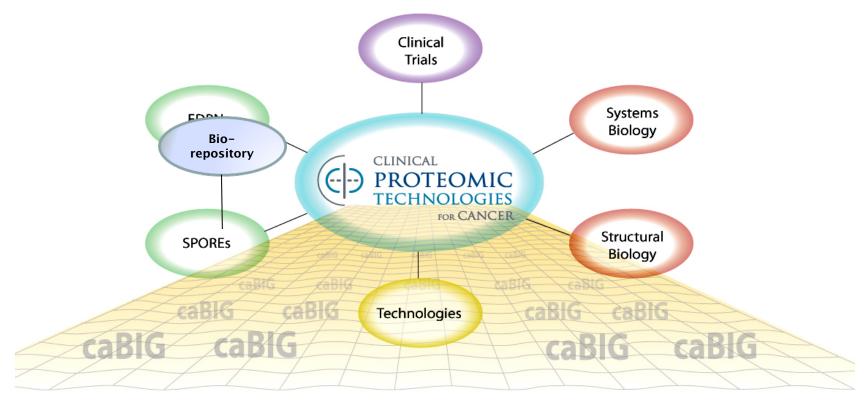


Bindley Activities

Research projects	Cancer research and biomarkers
	Infectious diseases
	Biofuels
	Bionanotechnology
	Instrument technology
Corporate interactions	Expertise for corporate projects
	Facilitate start-ups
	Access to capabilities
Equipment & research	'Omics technologies
capabilities	Screening, detection
	Sensors, MEMS
	Flow, sorting, imaging
	Data integration
Engagement & outreach	Regional corporate development
	Global partnerships

Research areas - cancer





- 'omics analyses CPTAC (National Cancer Insitute), Cancer Care Engineering, Multiple Myeloma Reseach foundation funding
- methods development
- biorepository
- flow/sorting
- screening & drug discovery

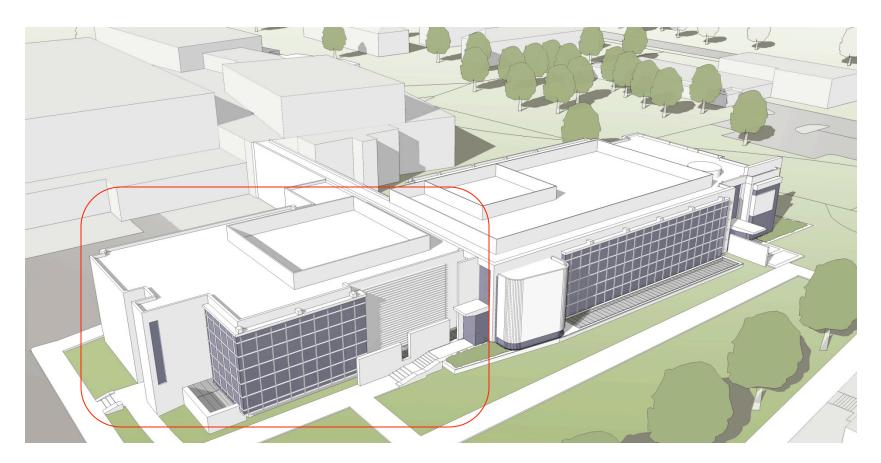
- Center for global intervention in infectious disease, cGRIID
 - viruses, vectors, structural biology, insecticide discovery with novel targets
- Method development for molecular detection
- Vaccine development
- Instruments for research and diagnostics/therapeutics



Research service (cores)

- Biological mass spectrometry
 - small molecules, proteins: profiling and targeted analyses
- Biophysics
 - molecular interactions, SPR, Isothermal calorimetry
- Flow cytometry, cell sorting and selection
 - surface attached and suspension cell purification (BL2)
- Imaging (bioscience imaging facility)
 - new and state-of-the-art: microscopic and whole animal
- Integrated screening technologies
 - automation: high throughput screening and expression cloning
- In vivo pharmacology (swine)
 - stress-free sampling and dosing: unique capability
- Informatics and data management
 - custom approaches for handling and mining data

Coming soon ...



Bindley II addition – NIH C06 award \$14.9M, April 2010 – occupancy expected Fall of 2013 A multidisciplinary cancer and disease research facility

Directed Irradiation Synthesis: manipulating matter in nanoscale self-organized systems

J.P. Allain^{1,2,3}

O. El-Atwani^{1,2}, S. Suslov, S. Ortoleva³, B. Heim¹, D.L. Rokusek, E. Yang, C.N. Taylor, A. Cimaroli, A. Suslova, N. Samuelson, E.K. Walker¹, D. Zigon¹

¹School of Nuclear Engineering ²School of Materials Science and Engineering School of Biomedical Engineering ³Birck Nanotechnology Center

> Seminario Nanociencia 2010 Barranquilla, Colombia 21-23 October, 2010





Outline

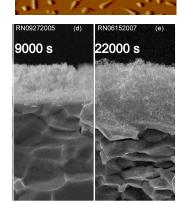
- Motivation for in-situ irradiated surface characterization
 - self-organized vs disordered systems
- In-situ observation and manipulation tool set
- Case studies of irradiation-driven systems:
 - nanolithography with 13.5-nm EUV radiation
 - lithium-doped graphitic surfaces in fusion devices
 - compound semiconductor nano-patterning
- Summary

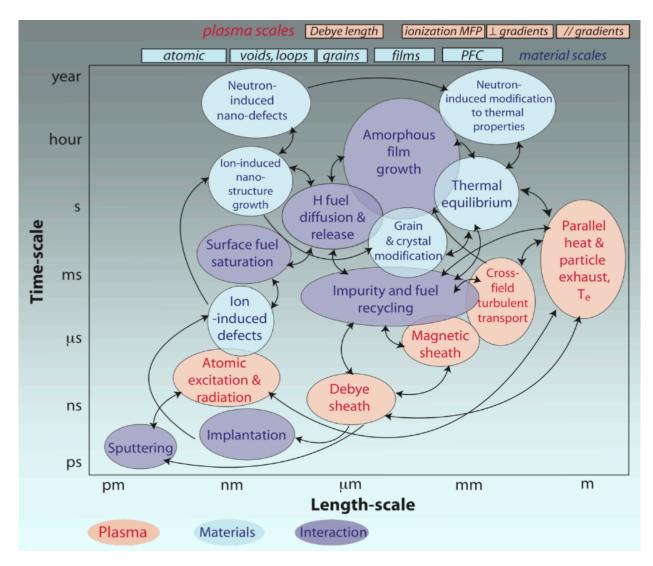




Irradiation-driven vs thermal-activated systems: instabilities and self-organization at the plasma-surface interface



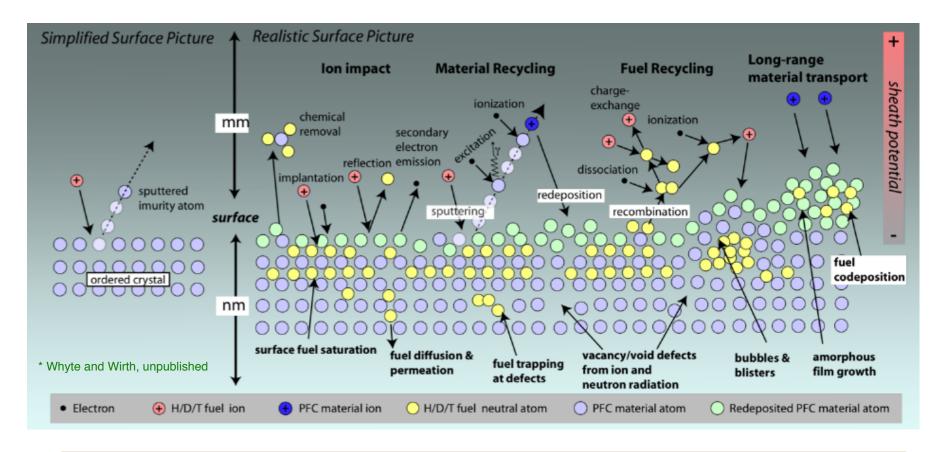






Courtesy of: B. Wirth and D.G. Whyte

Moving from a simplified view of the plasmasurface interface to a more rich and complex

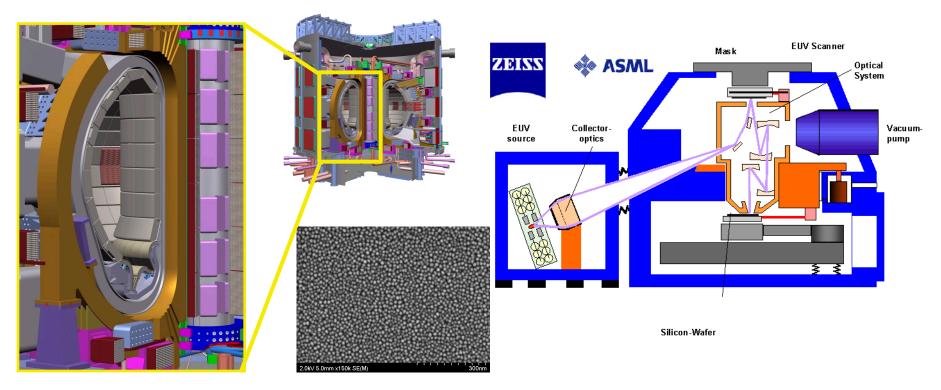


The complexity of the extreme PSI environment requires a more complex set of characterization tools that must probe *dynamically* ultra-shallow regions





Irradiation environments at near-sputter threshold energies



- In the plasma edge of a nuclear fusion reactor, the plasma boundary with the wall surface and sub-structure controls the inventory of hydrogen fuel
- Collector mirror surface of 13.5-nm light from high-density plasma sources
- Irradiation-driven nano-structures are primarily dictated by the sputter depth and surface relaxation mechanisms

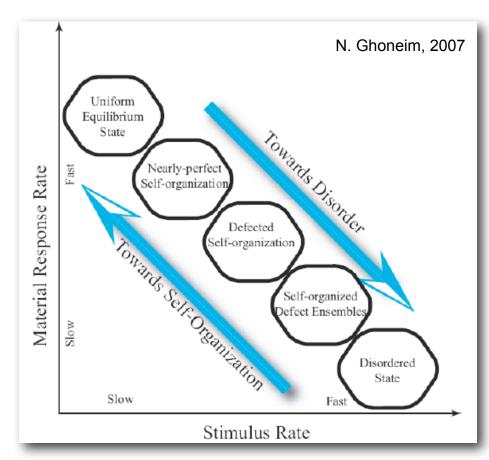


Driving matter between disorder and self-

organization

ion-induced damage
(e.g. fusion PMI*)

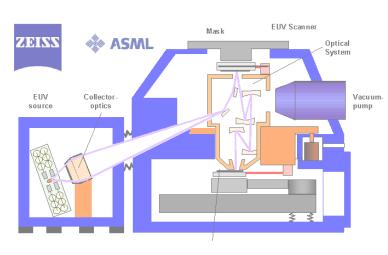
exploiting irradiationmatter interactions to synthesize new structures



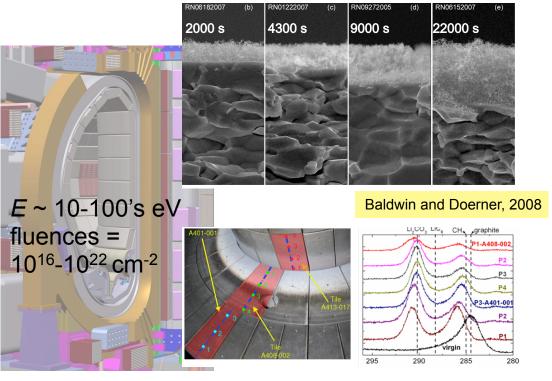
- Irradiation of matter (stimulus) leads to modification of matter inducing selforganized structures or disordered state (i.e. deterioration of properties)
- Understand how to manipulate matter (*directed irradiation synthesis*) to modify structure at nanoscale for new properties

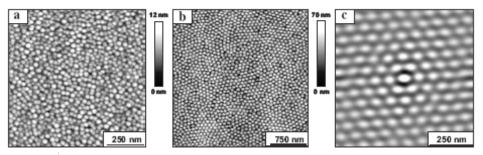


Spatial and energy scales of irradiation-driven systems under near-threshold sputter regime

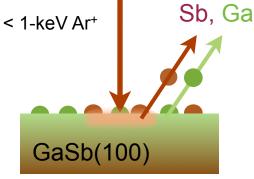


 $E \sim 100-1000$'s eV fluences = $10^{16}-10^{19}$ cm⁻²



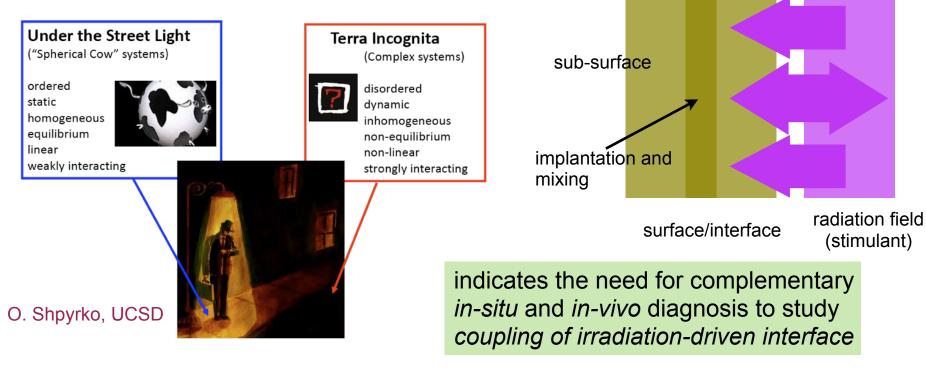


 $E \sim 10-100$'s eV, fluences = $10^{14}-10^{18}$ cm⁻²





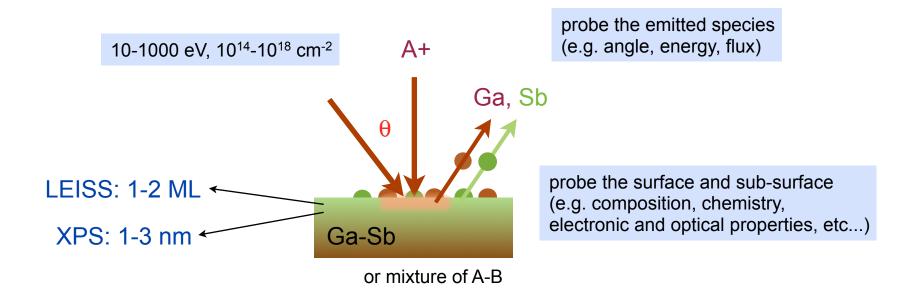
Critical knowledge gap between "real" or "complex" systems and "isolated" systems in condensed matter



- Understanding of complex matter in low-dimensional state systems limited by "probing" and "manipulating" approaches
- Need for dynamic measurement of surfaces under controlled irradiation fields
- Indicates the need for complementary in-situ and in-vivo diagnosis to study coupling of irradiation-driven interface



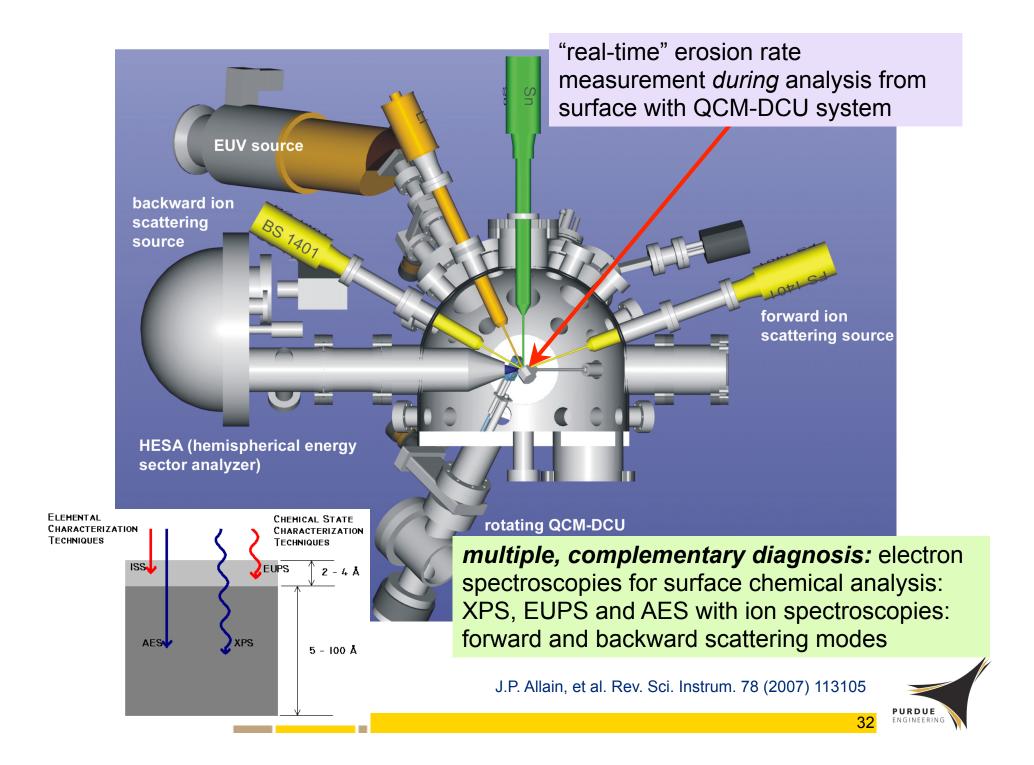
The Tool Set: In-situ characterization of an irradiation-driven surface



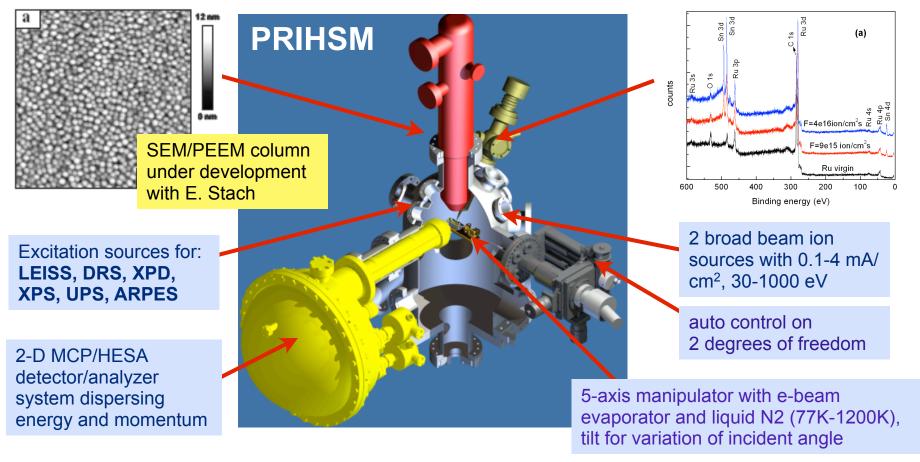
- amorphous layer: low-energy ion scattering spectroscopy (LEISS) in backscattering mode with 1.5-keV He ions
- sub-surface layer (1-5 nm) with XPS
- We combine the two techniques in-situ during irradiation with various modification sources







Modification ion sources with in-situ tool set

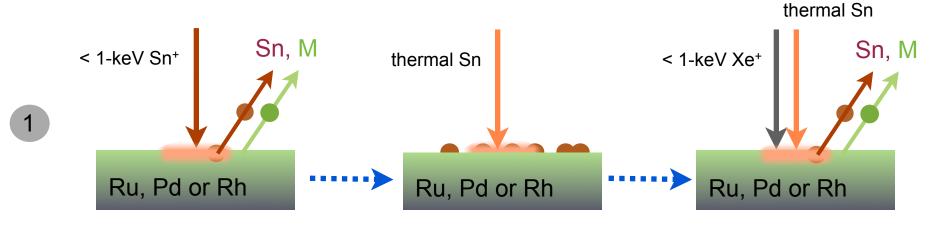


- Conditions: GaSb(100) samples irradiated by Ar+ at 50, 100 and 200 eV, normal incidence with 40-50 μAcm⁻² for fluences up to 10¹⁸ cm⁻²
- We operate in the sputter threshold regime and study early stage growth

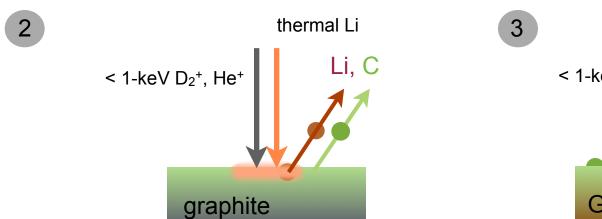


- e.g. $\sim 10^{15}$ - 10^{17} cm⁻²

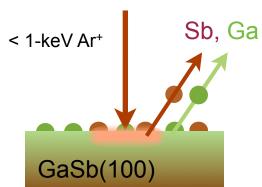
Case Studies: in-situ surface characterization of irradiation-driven surfaces



morphology, phase transformations, preferential sputtering



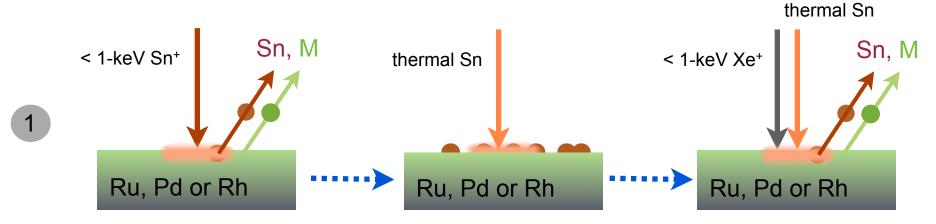
reactivity of Li, C and D with oxygen



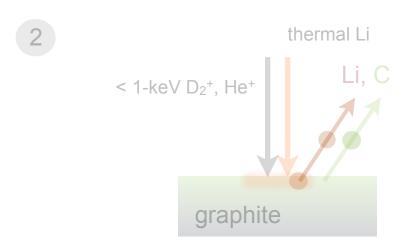
preferential sputtering, morphology



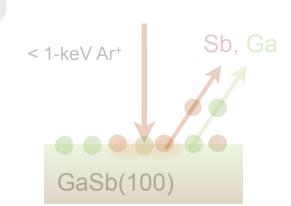
Case Studies: in-situ surface characterization of irradiation-driven surfaces



morphology, phase transformations, preferential sputtering



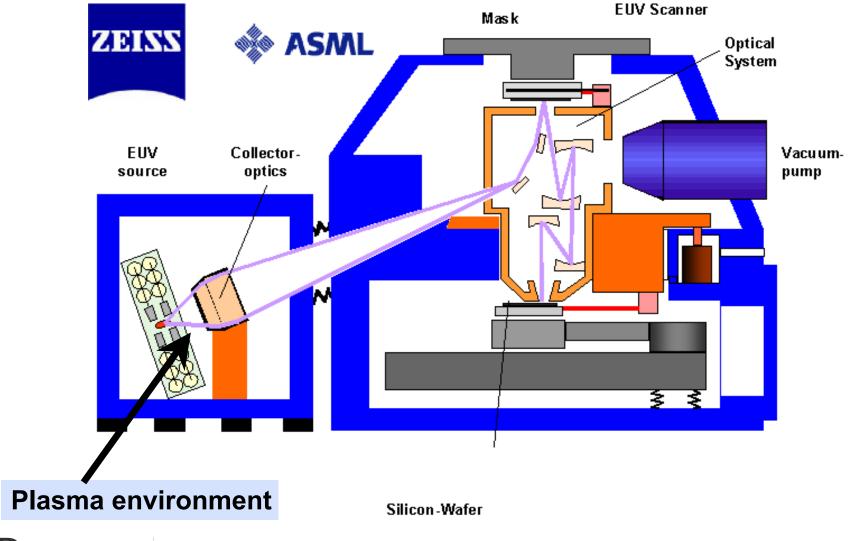
reactivity of Li, C and D with oxygen

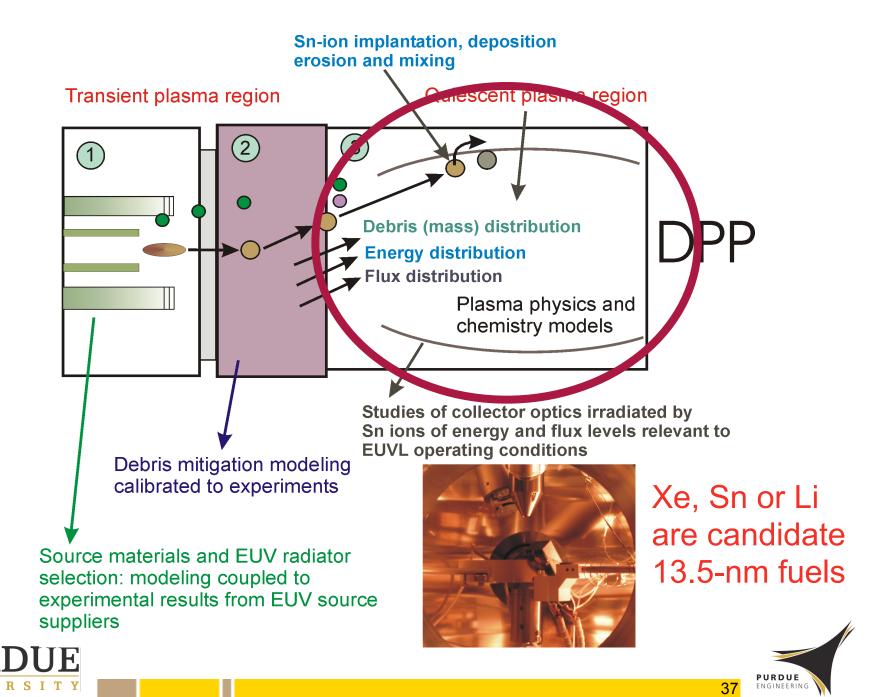


preferential sputtering, morphology

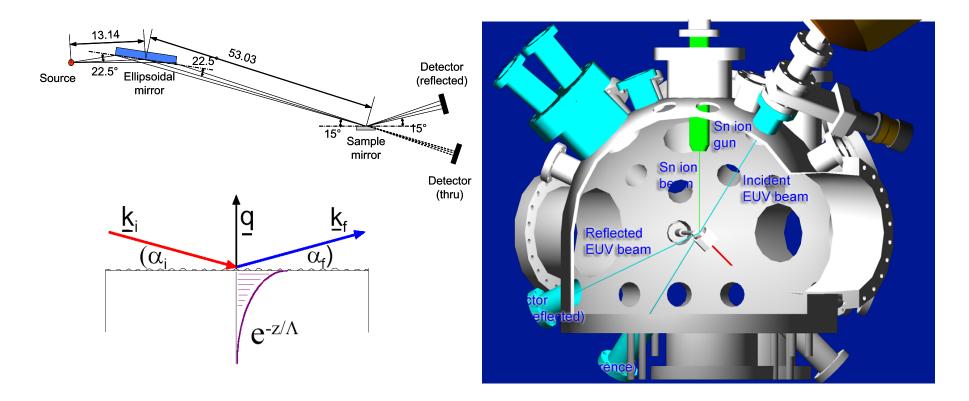


EUVL-Scanner: schematic





EUV reflectometry for grazing incidence mirror studies

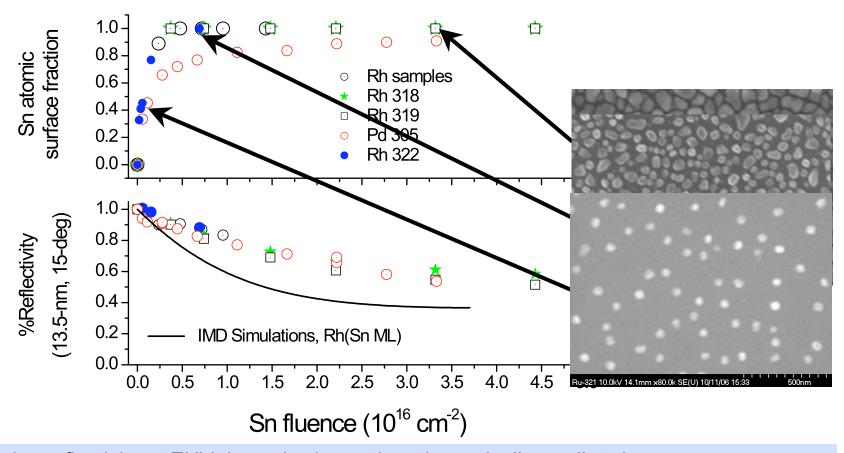


The In situ EUV reflectometry system in IMPACT diagnoses the reflectivity response of candidate mirrors during irradiation of Sn ions or thermal atoms and measurement of the chemical and elemental state of the mirror surface





In-situ surface elemental evolution and EUV reflectivity during exposure to thermal Sn

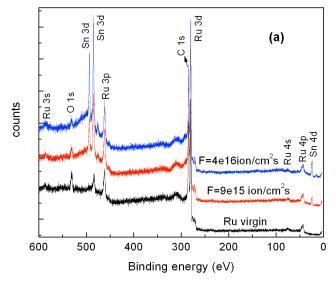


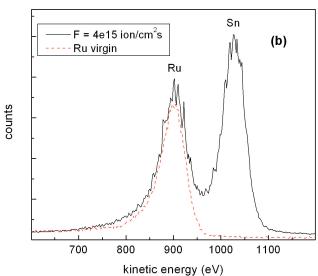
- Relative reflectivity at EUV decay is slower than theoretically predicted
- In-situ measurements indicate that this is due to partial coverage of Sn deposition on the mirror surface due to the coalescence of Sn islands during exposure

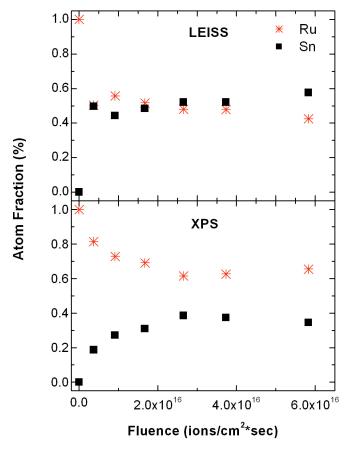




Probing spatial scales with complementary surface-sensitive techniques



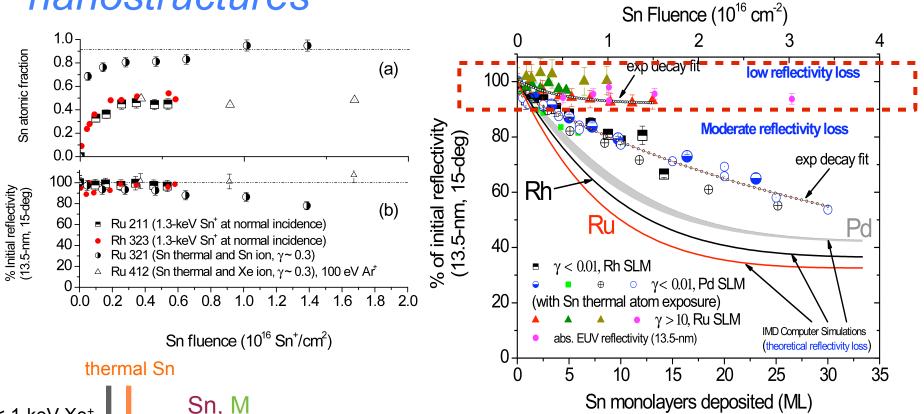


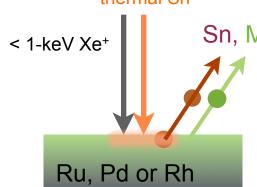


- 1.3-keV Sn⁺ on Ru mirror surfaces implanted at normal incidence
- Note the distinct probing regions of XPS vs LEISS



Ion and atom balance induce complex nanostructures





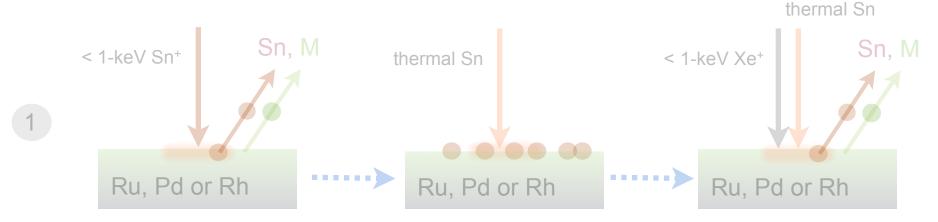
Balance of ion implantation with erosion against the thermal deposition of Sn atoms can aid in "tuning" Sn concentration on surface and EUV reflectivity loss



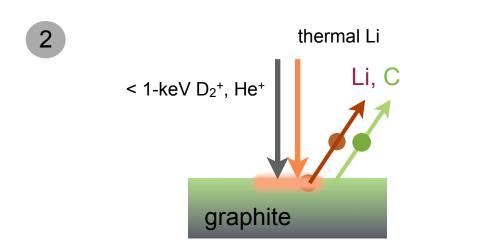
Absolute 13.5-nm reflectivity ex-situ



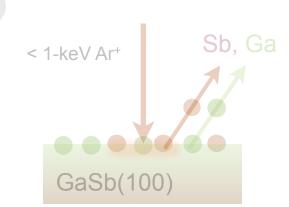
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morphology, phase transformations, preferential sputtering



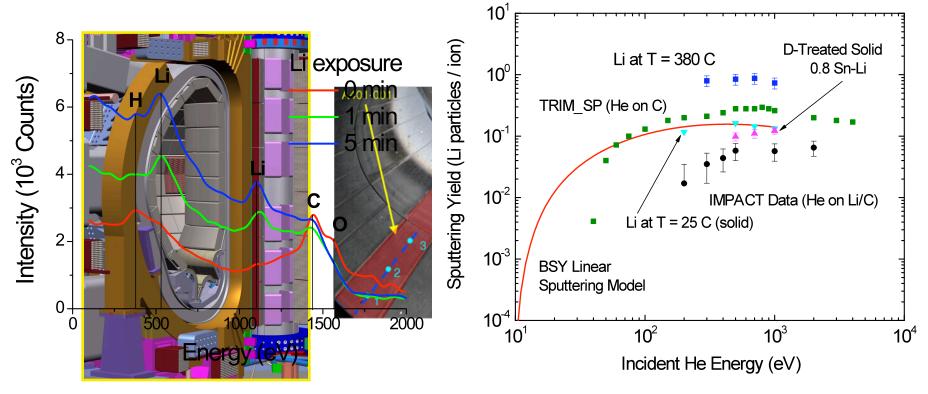
reactivity of Li, C and D with oxygen



preferential sputtering, morphology



Lithium coatings on graphite: surface effects on erosion, particle retention



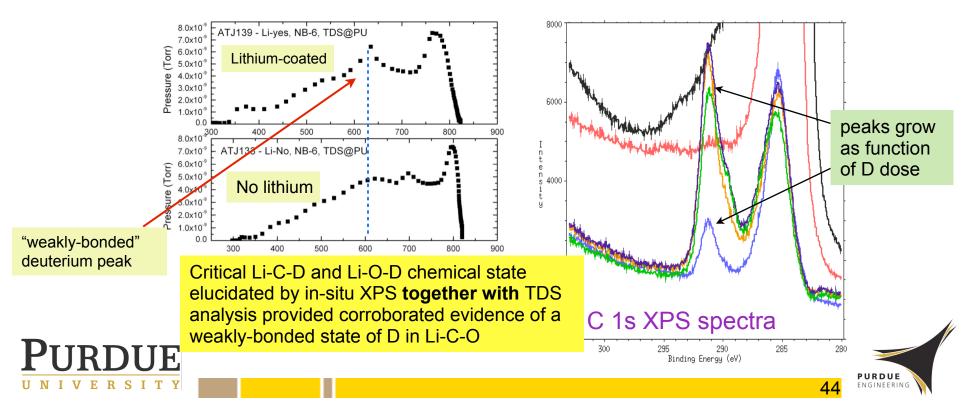
- Lithium intercalates to the basal planes of graphite. Difficult to maintain 100% lithium layers on top few ML. Oxygen typically bound with lithium
- Substantial reduction of both *physical* and *chemical* sputtering by *D* or *He* bombardment when comparing lithiated graphite surfaces to either pure Li or C



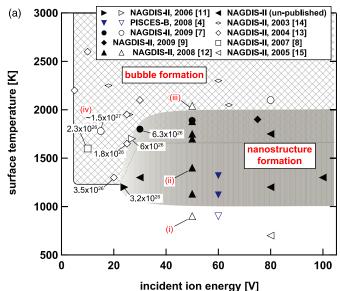


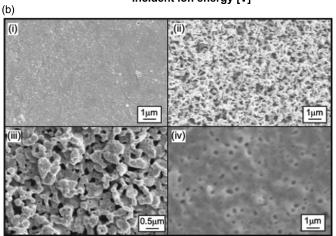
In fusion reactors, manipulation of hydrogen isotopes in a region of a few 10's of nm to order of µm's

- Critical to the recycling of D when using lithium as a PFS (plasmafacing surface) is the top layer of atoms
- Sputtered particles emanate from the first 2-3 ML of a metal surface (although the damage zone can be 10-100's nm below)
- Recombination of implanted D occurs in the first few layers at the surface-vacuum interface dictating recycling to the plasma edge



Self-organization under nuclear fusion reactor conditions for He irradiation of tungsten



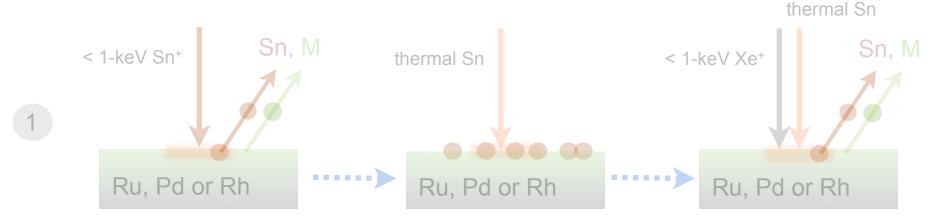


- Self-organized nanostructures under near-threshold energies (damage/sputtering)
- What are the consequences of such structures at the plasmasurface interface?
 - structures are in the spatial scale of implantation
 - effect on retention/recycling of hydrogen/helium
 - effect on erosion, recombination, surface diffusion
- New radiation resistant materials

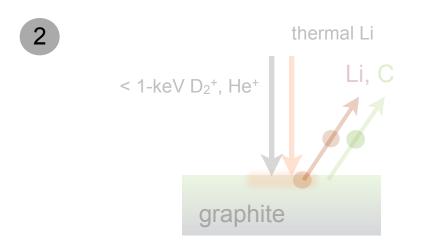




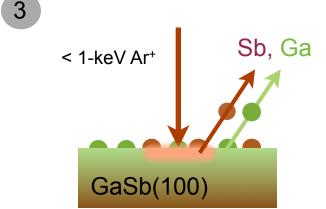
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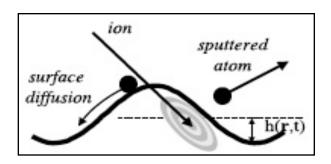


preferential sputtering, morphology



Self-organized structures and directed irradiation

synthesis

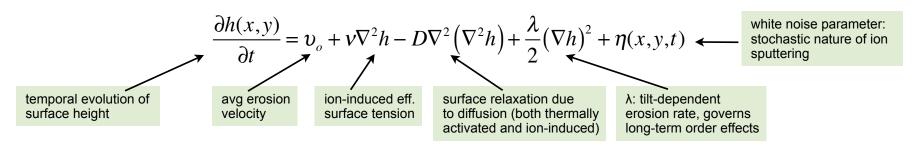


E. Chason et al. 2001. Nucl. Instrum. Methods B 178: 55-61.

(a) (c) (c) (d)

(a) Ripples on sand dunes in Morocco, (b) 3.7x6.7µm AFM image of Si surface immersed in argon plasma, (c) "dots" on a sand dune, (d) 1x1µm² AFM image of GaSb irradiated by 0.7-keV Ar+ ions under normal incidence.*

Kuramoto-Sivashinksky (KS) equation*:



- Forces and mechanisms driving self-organization in nano-structures.
- Pathway for ion-beam nanopatterning and functionalization of surfaces



*Javier Munoz-Garcia et al. 2009. Towards Functional Materials, Z.M. Whang ed.



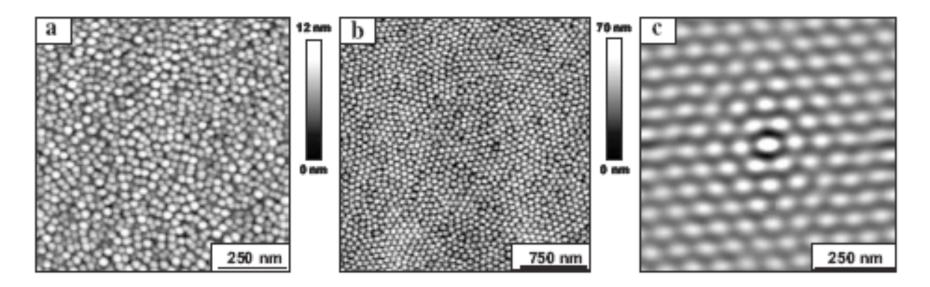
Motivation

- Models are elucidating on more complex mechanisms driving nanopatterning at low energies
- Erosion vs diffusive vs re-distributive mechanisms need to be better understood
- Correlation of surface nanopatterning to concentration evolution of multicomponent surfaces is poorly understood, in particular at energies approaching the sputter threshold (<100 eV)
- In-situ techniques may aid when coupled with computational modeling in deciphering the mechanisms that drive nanopatterning at energies approaching the sputter threshold
- What are the mechanisms driving nanopatterning of multi-component surfaces at energies at or below the sputter threshold?
 - Ar⁺ on GaSb at normal incidence¹:
 - Y(E=50eV) = 0.05; Y(E=100 eV) = 0.25





Nanopatterning III-V semiconductors



Fluence = 5×10^{16} cm⁻²

Fluence = 5×10^{17} cm⁻²

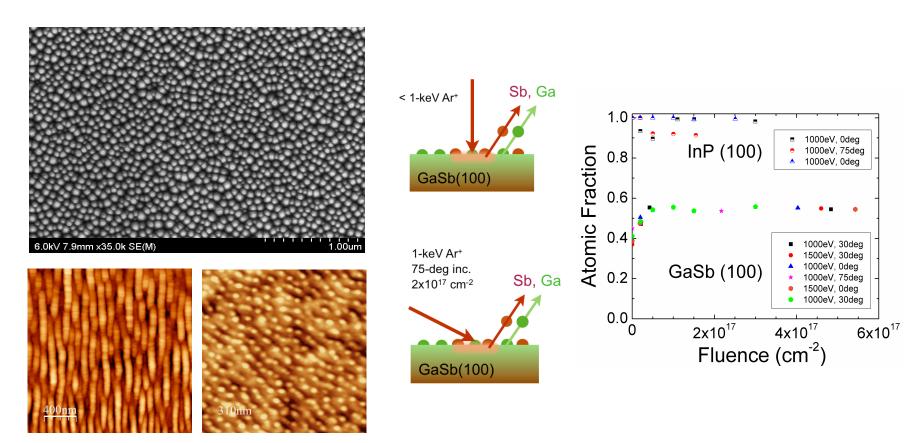
- Ion-induced morphology on semiconductor surfaces evolves and depends on irradiation fluence (dose)
- 500 eV Ar sputtering with 400 µA/cm² ion incidence at 40 degree-incidence on InP
- Ion sculpting can be used for surface templating or quantum dot fabrication



F. Frost and B. Rauschenbach, Appl Phys A 77, 1-9 (2003)



Evidence of threshold energy-induced morphology is complex and likely not explained by BH models

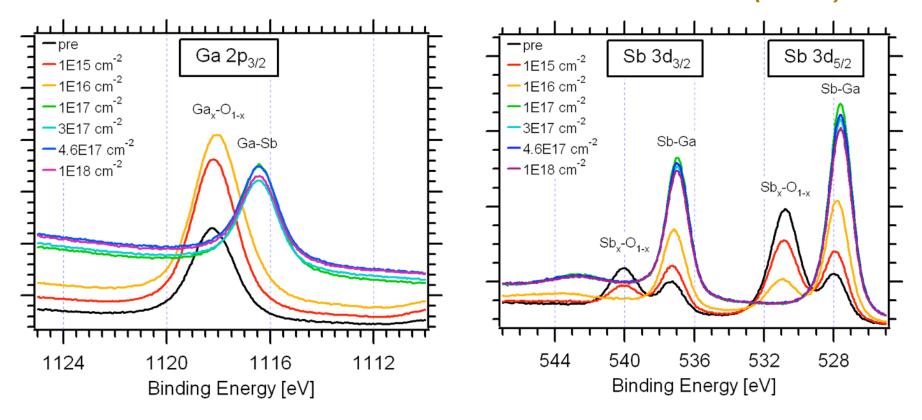


- Defect kinetics in the damaged zone could be critical to driving of the nanoscale structure on surface
- For energies studied 50-200 eV, this region in GaSb is only 0.6-1.6 nm





In-situ XPS results for irradiated GaSb(100)

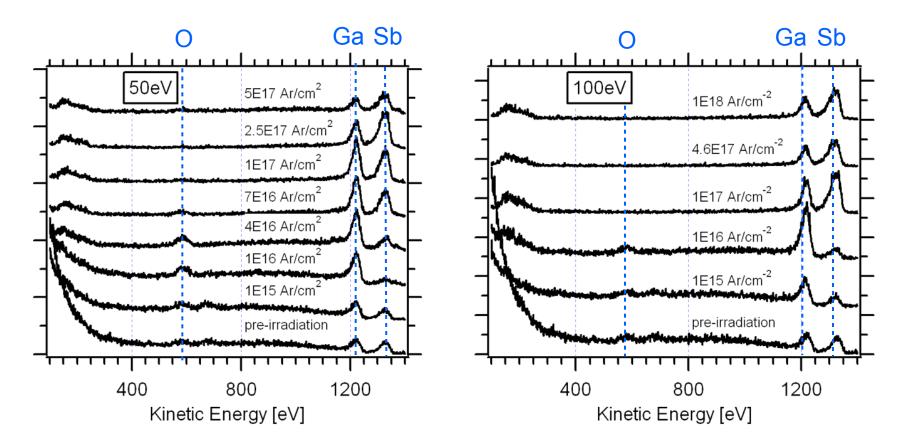


- XPS gives clear indication of Ga oxide as well as Sb oxide on subsurface region.
- between 10¹⁶ and 10¹⁷ cm⁻² clear indication that surface oxides are no longer dominant
- sub-surface shows only Ga-Sb bonding indicative of crystalline structure





In-situ LEISS results for irradiated GaSb(100)

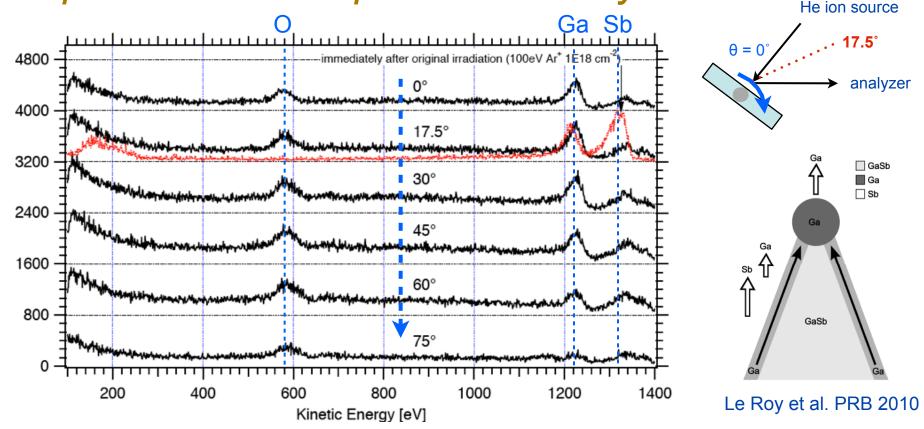


- Early stages evidence of Ga oxide predominantly on the first few ML
- From 10¹⁶ to 10¹⁷ cm⁻² a dramatic increase in Sb is evidenced
- Sb elastic lab cross section = 0.0065 A²/sr; Ga = 0.0102 A²/sr





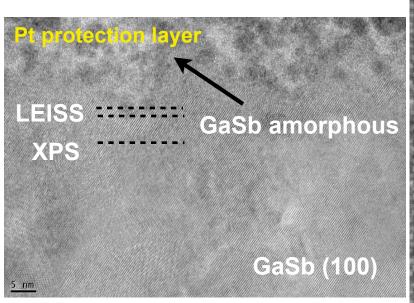
What happens with the irradiated samples exposed to atmosphere for analysis?

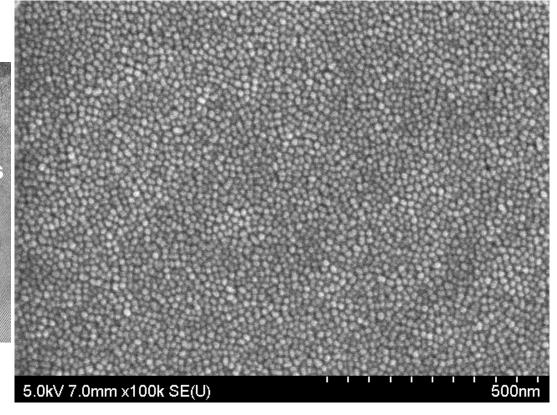


- Patterned sample exposed to air and returned for characterization after several days
- LEISS spectra for various tilts "probing" from the tip of the dot/pyramid to its sides
- When compared to non-contaminated data clear segregation of Ga to surface upon reduction of oxide (here the surface free energy is critical)



TEM and HR-SEM work on GaSb

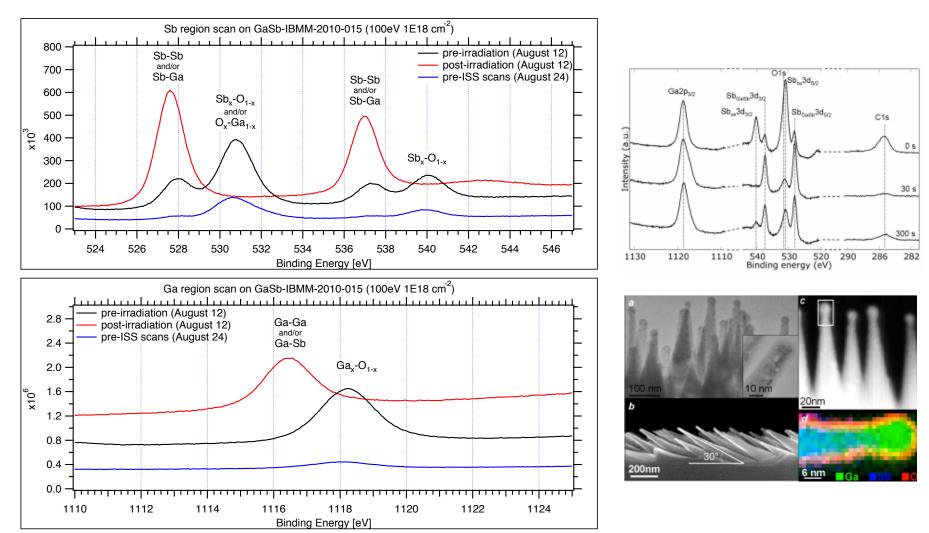




- 13-15 nm nanostructures synthesized by 50 eV Ar+ at normal incidence
- Top 1-1.2 nm is an amorphous layer and dominated by Sb atoms (LEISS)
- Subsurface is crystalline structure with stoichiometric 1:1 composition (XPS)





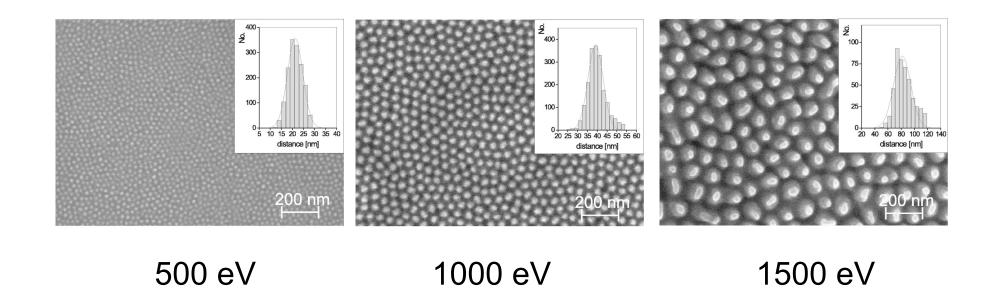


Le Roy et al. J. Appl. Phys 2009

In-situ characterization elucidated on mechanism for nanostructure formation and the role of an ultra-thin amorphous top layer



Ar+ on GaSb and role of incident particle energy on nanopattern

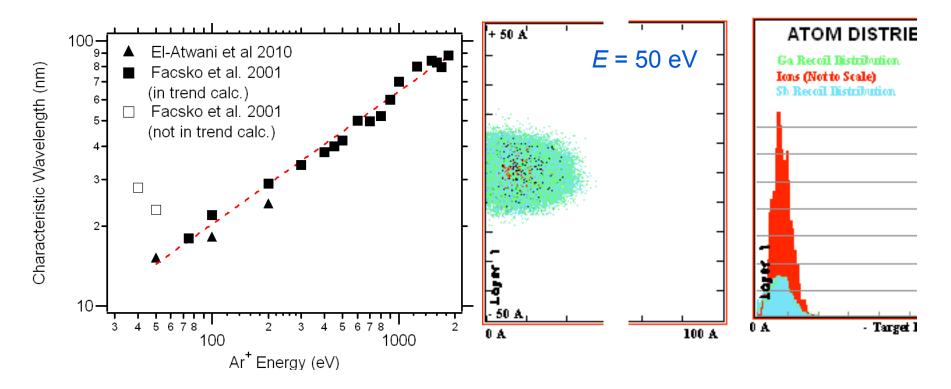


S. Facsko and H Kurz. Phys Rev B, 63 (2001) 165329.





Energy dependence of dot formation on GaSb

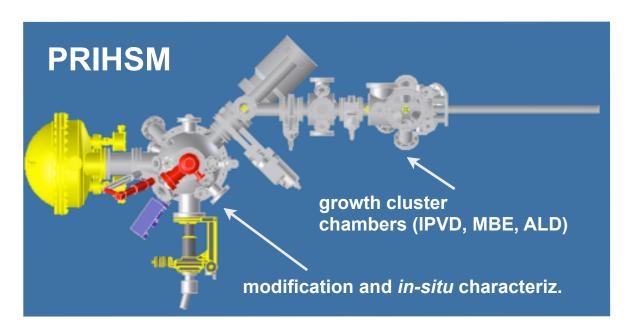


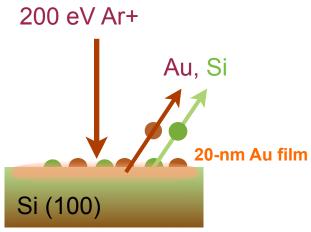
- Correlation between incident particle energy and characteristic "size" of nanostructures
- In this case "size" is measured as distance from center-to-center of the dots
- BCA based calculations (SRIM 2008) show damage region in first 1-2 nm,





Si(100) surface nanopatterning



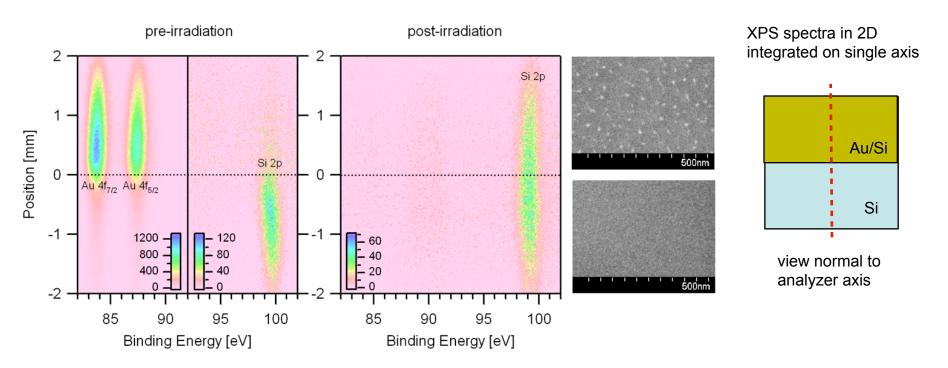


- Thin layers of Au deposited on Si(100) using MBE with various thicknesses from 3-30 nm.
- Au used as an immiscible component to study nanopattern formation on Si at normal incidence and near sputter-threshold energies (~50-200 eV)
- Irradiation up to 10¹⁸ cm⁻² and study with *in-situ* XPS, *ex-situ* SEM, AFM





Nanopatterning of Si(100) with ultra-thin Au films irradiated with 200 eV Ar+

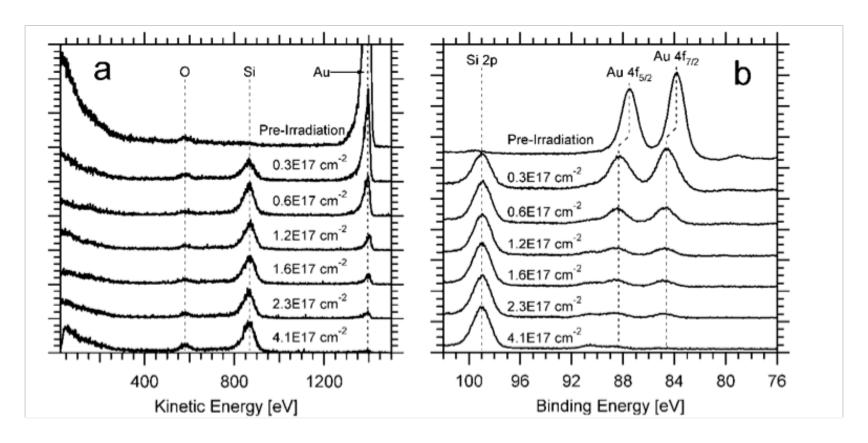


- 2D detector allows us to observe a macroscale-resolved scan. Half of Si(100) sampled masked and other half coated with thin Au film
- Irradiation at 200 eV Ar+ for 10¹⁸ fluence and normal incidence yields nanostructures only on region coated with gold
- In-situ XPS allows us to confirm that structures are not gold





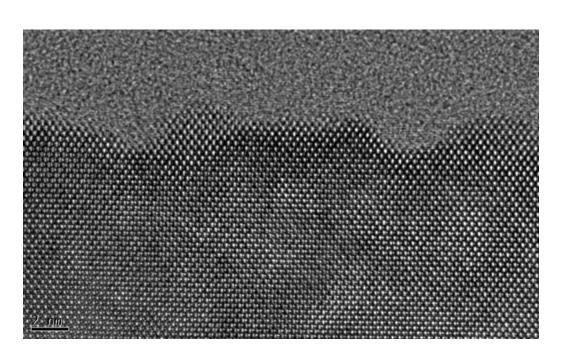
Formation of silicide induced nanopatterning of silicon elucidated by complementary surface-sensitive techniques

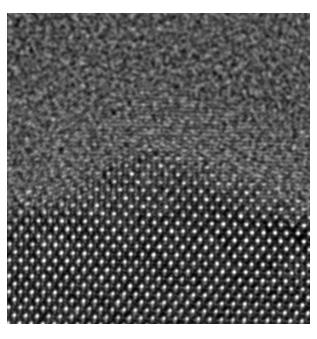






Si ordered nanostructures self-organized under low-energy irradiation

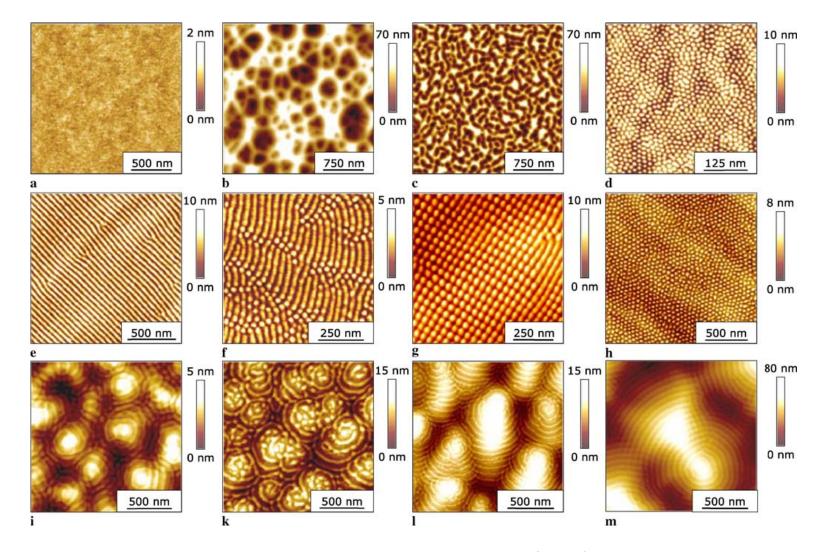




- 200 eV Ar+ ions are used at normal incident to the sample surface yielding at a threshold fluence of about 10¹⁷ cm⁻² (i.e. in only a few seconds...)
- One could scale up technique to combine nanopatterning and multi-layer coating deposition with ultra-thin films







By controlling near-threshold damage ion irradiation of surfaces one can attain a variety of nano-patterned surfaces. Simply varying incident angle, energy, species in a scalable and parallel nano-manufacturing approach





Summary

- In-situ surface characterization during particle irradiation can elucidate on relevant mechanisms of irradiation-driven self-organization
- Limiting factors of experimental approach lies on spatial and temporal scales probed
 - Use of complementary surface diagnostics
 - Complement with computational simulations
- Case studies demonstrate importance of ion-induced surface modification and implications on surface functionality (i.e. the case for 13.5-nm reflectivity)
- Correlating ion-induced nano-patterning to surface chemistry and elemental evolution can elucidate underlying mechanisms at particle energies near sputter threshold





Extra Slides





Thank You for your Attention



